NSN 5961-01-171-6688

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-171-6688 **Inclosure Material:** Glass **Overall Length:** 0.165 inches **Terminal Length:** 0.900 inches **Overall Diameter:** 0.065 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 reverse voltage, instantaneous and 450.0 reverse voltage, peak **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 1.00 amperes source cutoff current preset and 5.00 microamperes forward current, average peak **Capacitance Rating In Picofarads:** 40.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Leads silver **Precious Material:** Silver **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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